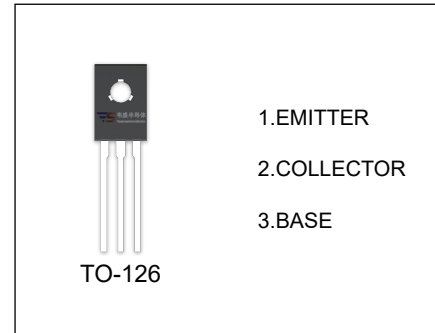


3CA8772 TRANSISTOR (PNP)

FEATURES

- High Current
- Low Voltage



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
3CA8772	TO-126	Bulk	200pcs/Bag
3CA8772-TU	TO-126	Tube	60pcs/Tube

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-40	V
V_{CEO}	Collector-Emitter Voltage	-30	V
V_{EBO}	Emitter-Base Voltage	-6	V
I_C	Collector Current	-3	A
P_C	Collector Power Dissipation	1.25	W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	100	$^{\circ}\text{C}/\text{W}$
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}\text{C}$

$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-100\mu\text{A}, I_E=0$	-40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-10\text{mA}, I_B=0$	-30			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-100\mu\text{A}, I_C=0$	-6			V
Collector cut-off current	I_{CBO}	$V_{CB}=-40\text{V}, I_E=0$			-10	μA
Collector cut-off current	I_{CEO}	$V_{CE}=-30\text{V}, I_B=0$			-10	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=-6\text{V}, I_C=0$			-10	μA
DC current gain	h_{FE}	$V_{CE}=-2\text{V}, I_C=-1\text{A}$	60		400	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-2\text{A}, I_B=-0.2\text{A}$			-0.5	V
Transition frequency	f_T	$V_{CE}=-5\text{V}, I_C=-0.1\text{A}, f=10\text{MHz}$	50			MHz

CLASSIFICATION OF h_{FE}

RANK	R	O	Y	GR
RANGE	60-120	100-200	160-320	200-400